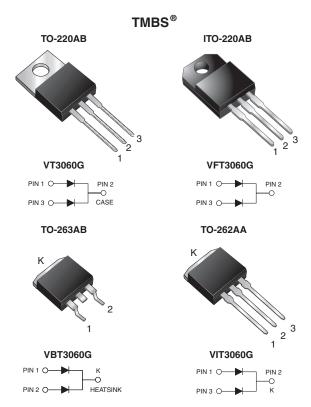
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# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

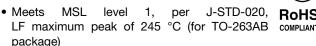
Ultra Low  $V_F = 0.40 \text{ V}$  at  $I_F = 5 \text{ A}$ 



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
$V_{RRM}$	60 V					
I <sub>FSM</sub>	150 A					
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.61 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Circuit configuration	Common cathode					

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation



- Not recommended for PCB bottom side wave mounting
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT3060G	VFT3060G	VBT3060G	VIT3060G	UNIT	
Max. repetitive peak reverse voltage	V <sub>RRM</sub>	60						
Max. average forward rectified current	per device		30					
(fig. 1)	per diode	I <sub>F(AV)</sub>	15					
Peak forward surge current 8.3 ms single has superimposed on rated load	If sine-wave	I <sub>FSM</sub>	150			Α		
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode		E <sub>AS</sub> 120				mJ		
Peak repetitive reverse current at $t_p = 2 \mu s$ , 1 kHz, $T_J = 38 ^{\circ}\text{C} \pm 2 ^{\circ}\text{C}$ per dic	' lppu			Α				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500				V	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150				°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	60 (min.)	-	V		
Instantaneous forward voltage per diode (1)	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C		0.49	-	V		
	I <sub>F</sub> = 7.5 A			0.53	-			
	I <sub>F</sub> = 15 A			0.65	0.73			
	I <sub>F</sub> = 5 A			$V_{F}$	0.40	-	V	
	I <sub>F</sub> = 7.5 A		C	0.46	-			
	I <sub>F</sub> = 15 A			0.61	0.69			
Reverse current per diode (2)	V <sub>R</sub> = 60 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	- 14	850 40	μA mA		

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT3060G	VFT3060G	VBT3060G	VIT3060G	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	3.2	6.2	3.2	3.2	°C/W	
Typical inermal resistance	per device		1.9	5.0	1.9	1.9	C/VV	

ORDERING INFORMATION (EXAMPLE)									
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
TO-220AB	VT3060G-E3/4W	1.88	4W	50/tube	Tube				
ITO-220AB	VFT3060G-E3/4W	1.76	4W	50/tube	Tube				
TO-263AB	VBT3060G-E3/4W	1.39	4W	50/tube	Tube				
TO-263AB	VBT3060G-E3/8W	1.39	8W	800/reel	Tape and reel				
TO-262AA	VIT3060G-E3/4W	1.45	4W	50/tube	Tube				

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

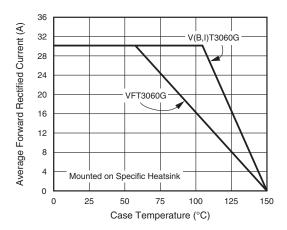


Fig. 1 - Maximum Forward Current Derating Curve

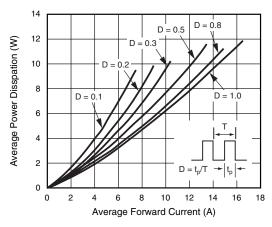


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

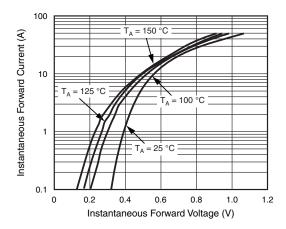


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

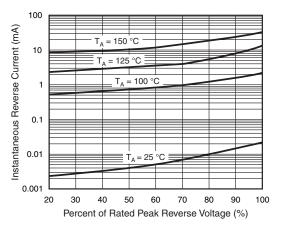


Fig. 4 - Typical Reverse Characteristics Per Diode

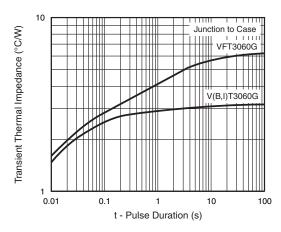


Fig. 5 - Typical Transient Thermal Impedance Per Diode

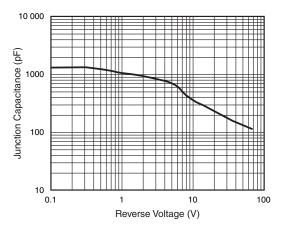
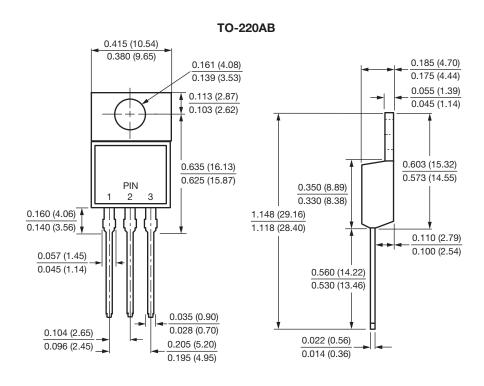


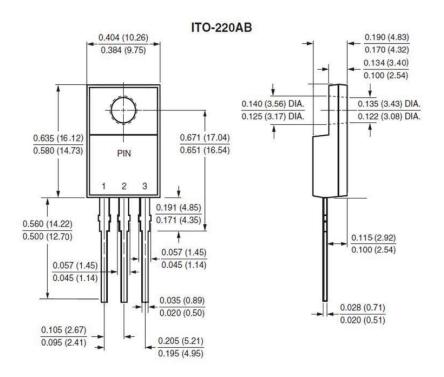
Fig. 6 - Typical Junction Capacitance Per Diode

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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

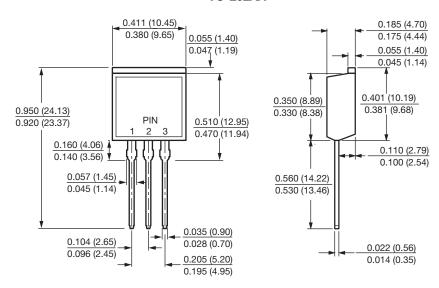




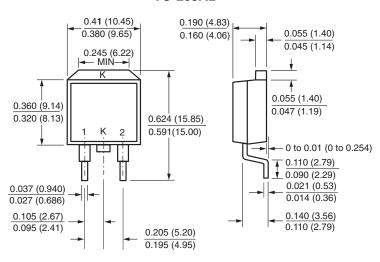
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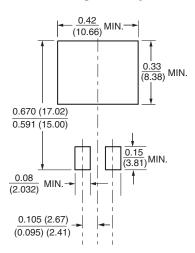
#### **TO-262AA**



#### **TO-263AB**



#### **Mounting Pad Layout**





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